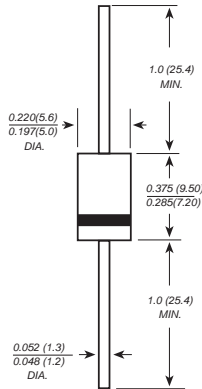


# SR320 THRU SR3200

## SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 3.0 Amperes

### DO-201AD



Dimensions in inches and (millimeters)

### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:  
250°C/10 seconds, 0.375" (9.5mm) lead length,  
5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** JEDEC DO-201AD molded plastic body

**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Mounting Position:** Any

**Weight:** 0.04 ounce, 1.10 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

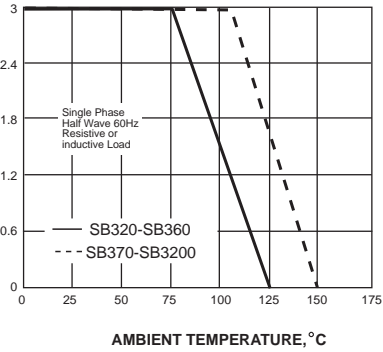
MDD Catalog Number	SYMBOLS	SB 320	SB 330	SB 340	SB 350	SB 360	SB 370	SB 380	SB 390	SB 3B0	SB 3150	SB 3200	UNITS	
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	50	60	70	80	90	100	150	200	VOLTS	
Maximum RMS voltage	$V_{RMS}$	14	21	28	35	42	49	56	63	70	105	140	VOLTS	
Maximum DC blocking voltage	$V_{DC}$	20	30	40	50	60	70	80	90	100	150	200	VOLTS	
Maximum average forward rectified current 0.375" (9.5mm) lead length(see fig. 1)	$I_{AV}$	3.0											Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	80.0											Amps	
Maximum instantaneous forward voltage at 3.0A	$V_F$	0.55		0.70		0.85			0.95			Volts		
Maximum DC reverse current at rated DC blocking voltage	$I_R$	0.5					0.2			0.2			mA	
$T_A=25^\circ\text{C}$ $T_A=100^\circ\text{C}$		20.0			10.0			2.0						
Typical junction capacitance (NOTE 1)	$C_J$	250			160									pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	40.0											°C/W	
Operating junction temperature range	$T_J$	-65 to +125					-65 to +150						°C	
Storage temperature range	$T_{STG}$	-65 to +150											°C	

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

AVERAGE FORWARD RECTIFIED CURRENT,  
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,  
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

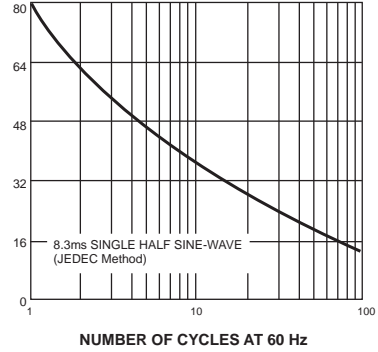
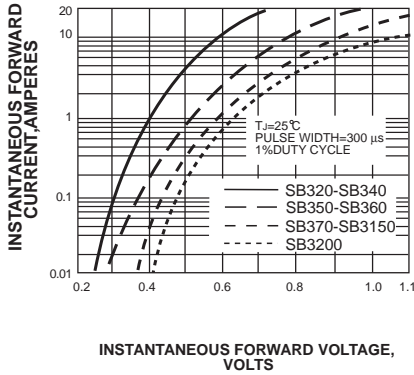


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS REVERSE CURRENT,  
MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS

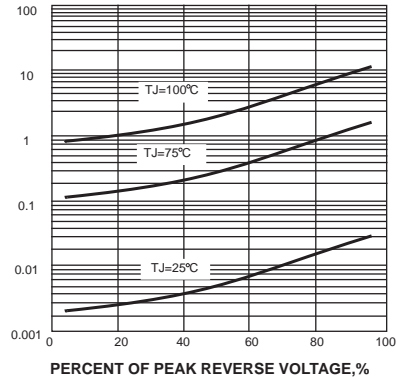
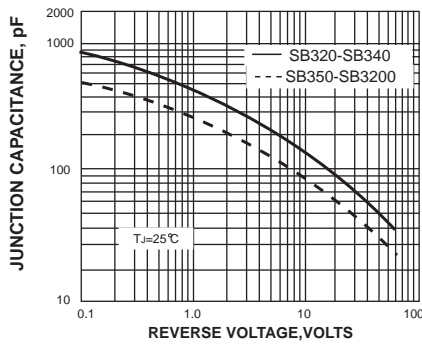


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,  
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

